



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: 1765
Confirmation No.: 8712
Examiner: Not yet assigned

In Re PATENT APPLICATION OF

Applicant(s): Erik JANZÉN *et al.*

Appl'n No.: 10/830,047

Filing Date: April 23, 2004

For: DEVICE AND METHOD FOR
PRODUCING SINGLE CRYSTALS BY
VAPOR DEPOSITION

Att'y Dkt.: 35947-202834

INFORMATION DISCLOSURE STATEMENT

26694
U.S. PATENT AND
TRADEMARK OFFICE

September 10, 2004

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This is an Information Disclosure Statement submitted under 37 C.F.R. § 1.97 within the time specified under 37 C.F.R. § 1.97(b).

Enclosed is a PTO-1449 and copies of references cited therein. The relevance of the non-English references is as follows. The article by Lely is discussed in the specification. Also, European patent 0 787 822 is discussed in the specification, an English abstract translation of the abstract is provided and U.S. patent 6,299,683 corresponds thereto.

Applicants respectfully request the Examiner to consider the cited publications and make them of record.

Date: 9/10/04

Respectfully submitted,

Eric Furler

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Please type a plus sign (+) inside this box →

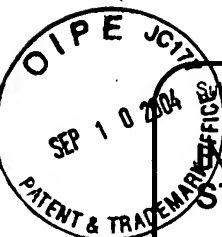


PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet 1 of 1

Complete if Known

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|------------------------|--------------------|
| Application Number | 0/830,047 |
| Filing Date | April 23, 2004 |
| First Named Inventor | Erik JANZEN et al. |
| Group Art Unit | 1765 |
| Examiner Name | tba |
| Attorney Docket Number | 35947-202834 |

U.S. PATENT DOCUMENTS

| Examiner Initials * | Cite No. ¹ | U.S. Patent Document | | Name of Patentee or Applicant of Cited Document | Date of Publication of Cited Document MM-DD-YYYY | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear |
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OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS

| Examiner Initials * | Cite No. ¹ | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. | T ² |
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Examiner
SignatureDate
Considered

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language translation is attached.

SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.

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